

Features

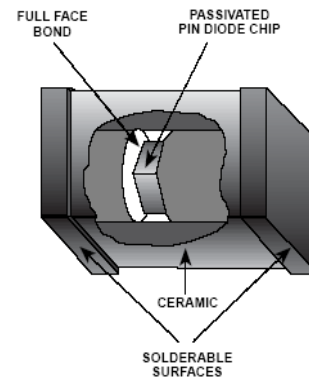
- ◆ Non-Magnetic Package Suitable for MRI Applications
- ◆ Rectangular MELF SMQ Ceramic Package
- ◆ Hermetically Sealed
- ◆ Low R_s for Low Series Loss
- ◆ Long τ_L for Lower Intermodulation Distortion
- ◆ Low C_j for High Series Isolation
- ◆ High Average Incident Power Handling
- ◆ RoHS Compliant

Description

The MA4P7461F-1072T is a surface mountable PIN diode in a non-magnetic, **Metal Electrode Leadless Faced (MELF)** package. The device incorporates M/A-COM Technology Solutions time proven HIPAX technology to produce a low inductance ceramic package with no ribbons or whisker wires. Incorporated in the package is a hard glass passivated, CERMACHIP™ PIN chip that is full face bonded on both the cathode and anode to maximize surface area for the lowest electrical and thermal resistance. The package utilizes a non-magnetic plating process that provides for a package with extremely low permeability. The MA4P7461F-1072T has been comprehensively characterized both electrically and mechanically to ensure repeatable and predictable performance. The non-magnetic MA4P7461F-1072T is the electrical equivalent of its magnetic counterpart the MA4P7001F-1072T.

Applications

This diode is well suited for use in low loss, low distortion, high power switching circuits and can be used in high magnetic field environments at HF through UHF frequencies. The low thermal resistance of this device provides excellent performance at high RF power incident levels, up to 100 watts CW. This device is designed to meet the most demanding electrical and mechanical MRI environments.



Designed for Automated Assembly

These SMQ PIN diodes are designed for high volume tape and reel assembly. The rectangular package design provides for highly efficient automatic pick and place assembly techniques. The parallel flat surfaces are suitable for key jaw or vacuum pickup. All solderable surfaces are tin plated and compatible with reflow and vapor phase soldering methods.

Absolute Maximum Ratings¹ @ 25°C

Parameter	Absolute Maximum
Operating Temperature	-65 °C to +125°C
Storage Temperature	-65 °C to +150°C
Diode Junction Temperature	+175 °C Continuous
Diode Mounting Temperature	+235°C for 10 seconds
RF C.W. Incident Power	+ 50 dBm C.W.
Forward D.C. Current	+ 250 mA
Reverse D.C. Voltage @ -10uA	1 - 100 V I

1. Exceeding these limits may cause permanent damage.

Electrical Specifications @ +25 °C

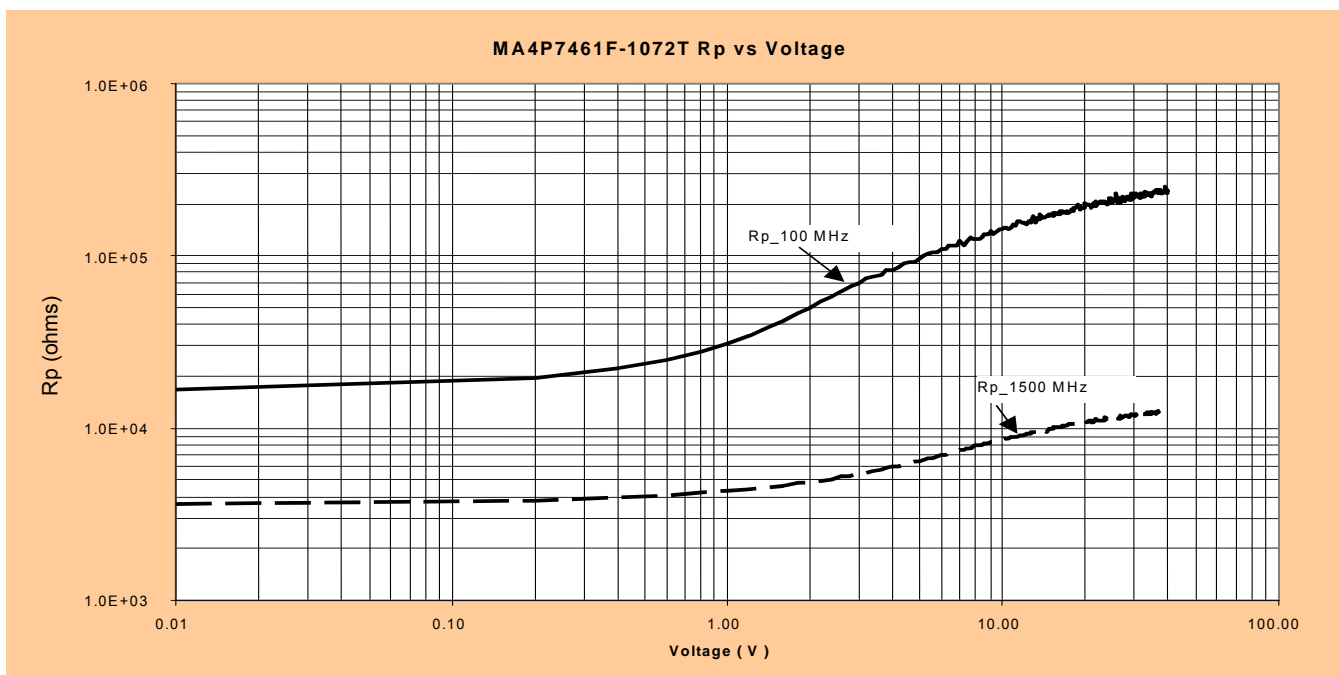
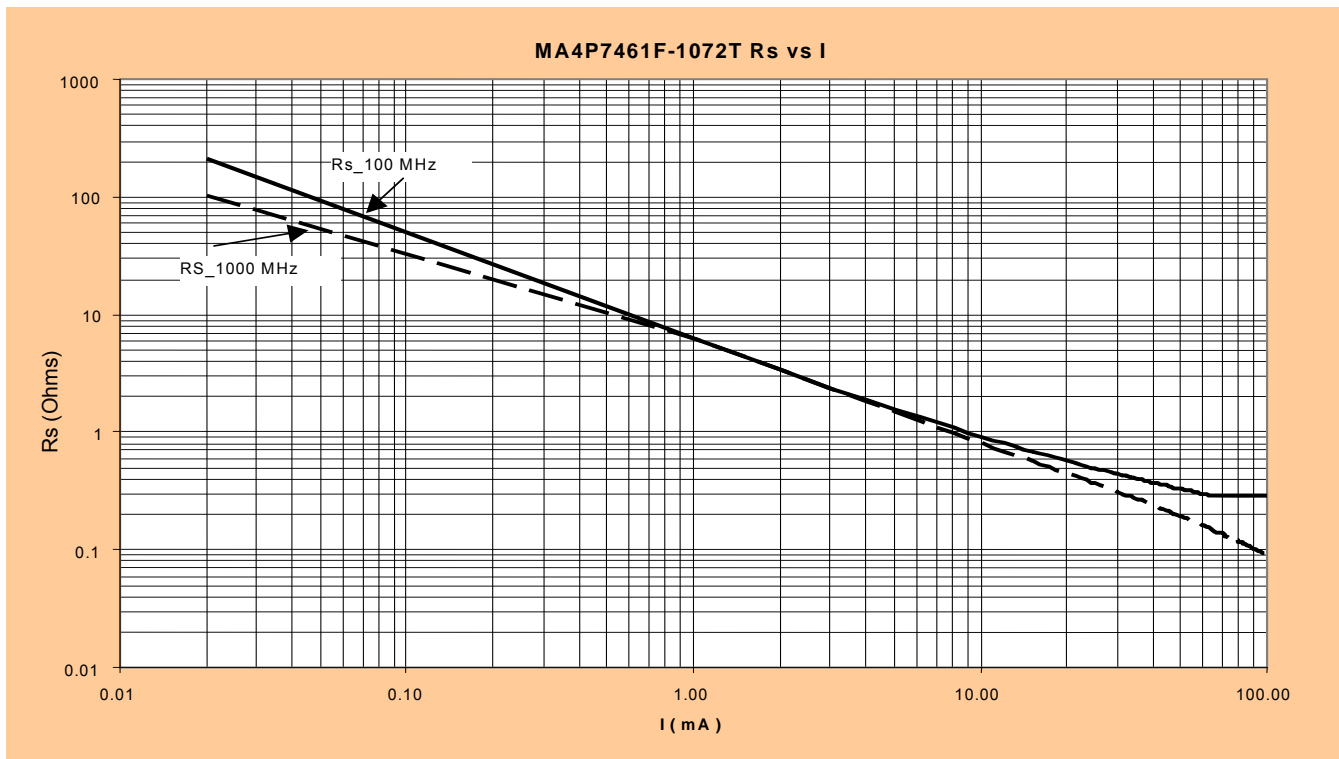
Parameter	Symbol	Condition	Unit Value
Forward Voltage (Maximum)	V_F	$I_F = +100\text{mA}$	$1.0V_{DC}$
Voltage Rating (Minimum)	V_R	$I_r = -10\mu\text{A}$	$ -100 V_{DC}$
Total Capacitance (Maximum)	C_T	$-100\text{V @ } 100\text{MHz}$	1.0 pF
Series Resistance (Maximum)	R_S	$+100 \text{ mA @ } 100\text{MHz}$	0.5Ω
Parallel Resistance (Minimum)	R_P	$-10 \text{ V @ } 100\text{MHz}$	$20\text{K } \Omega$
Carrier Lifetime (Nominal)	τ_L	$+6\text{mA} / -10\text{mA @}$ $(50\% - 90\% \text{ Voltage})$	$6.0\mu\text{s}$
I-Region Length (Nominal)	μm	-	$100\mu\text{m}$
C.W. Thermal Resistance (Maximum)	θ	-	15°C/W
Power Dissipation in Free Air (Maximum)	W	$I_F = +100\text{mA}$	3W
Power Dissipation (Maximum)	P_D	$I_F = +100\text{mA}$	8W

Environmental Capability

MELF devices are appropriate for use in industrial and military applications and can be screened to meet the environmental requirements of MIL-STD-750, MIL-STD-202 as well as other military standards. The table below lists some of the MIL-STD 750 tests the device is designed to meet.

Test	Method	Description
High Temperature Storage	1031	$+150^\circ\text{C}$, for 340 Hours
Temperature Shock	1051	-65°C to $+150^\circ\text{C}$, 20 Cycles
HTRB	1038	80% of rated V_B , $+150^\circ\text{C}$, for 96 Hours
Moisture Resistance	1021	No Initial Conditioning, 85% RH, $+85^\circ\text{C}$
Gross Leak	1071 Cond. E	Dye Penetrant Visual
Vibration Fatigue	2046	20,000G's, 60Hz, x, y, z axis
Solderability	2026	Test Temperature = $+245^\circ\text{C}$

Typical Electrical Performance @+25°C

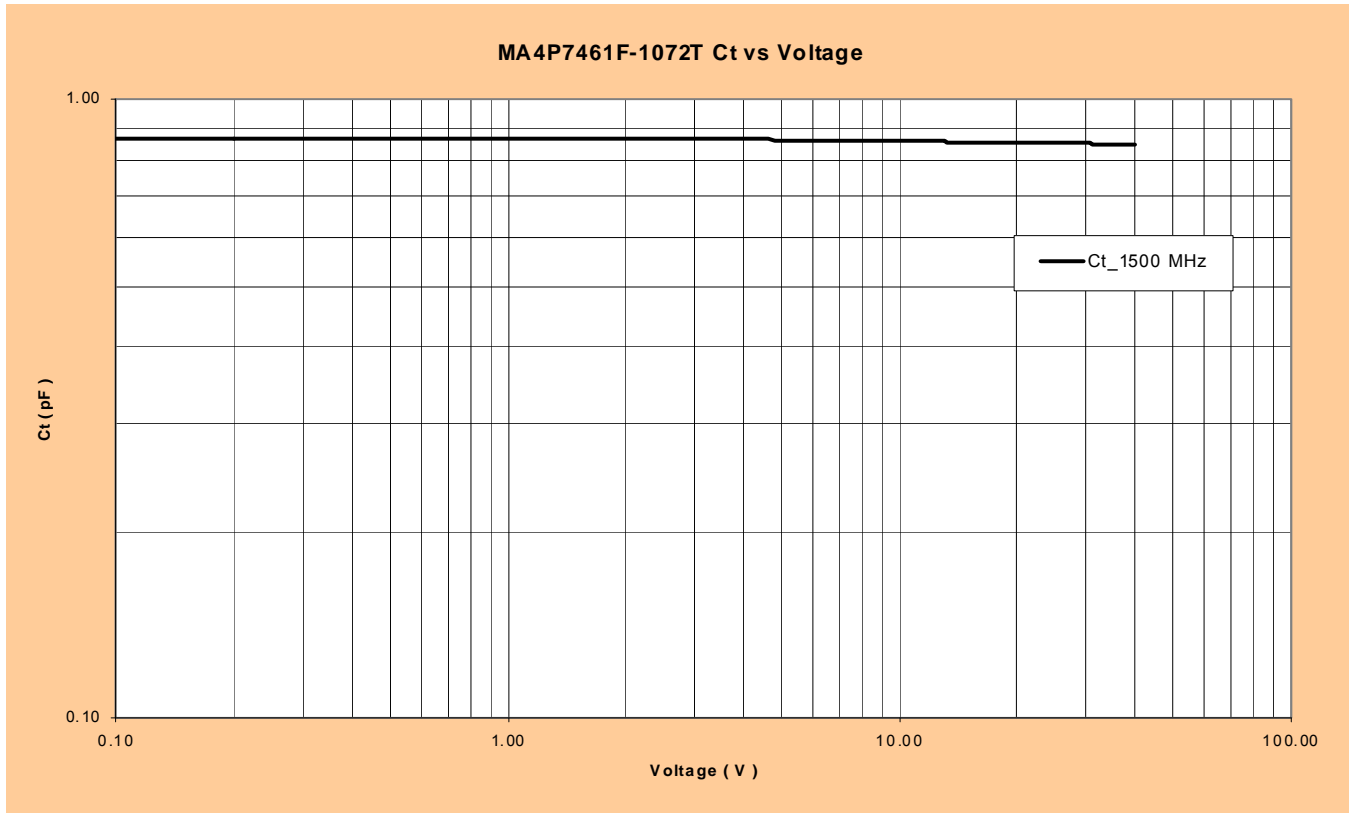


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- Visit www.macom.com for additional data sheets and product information.

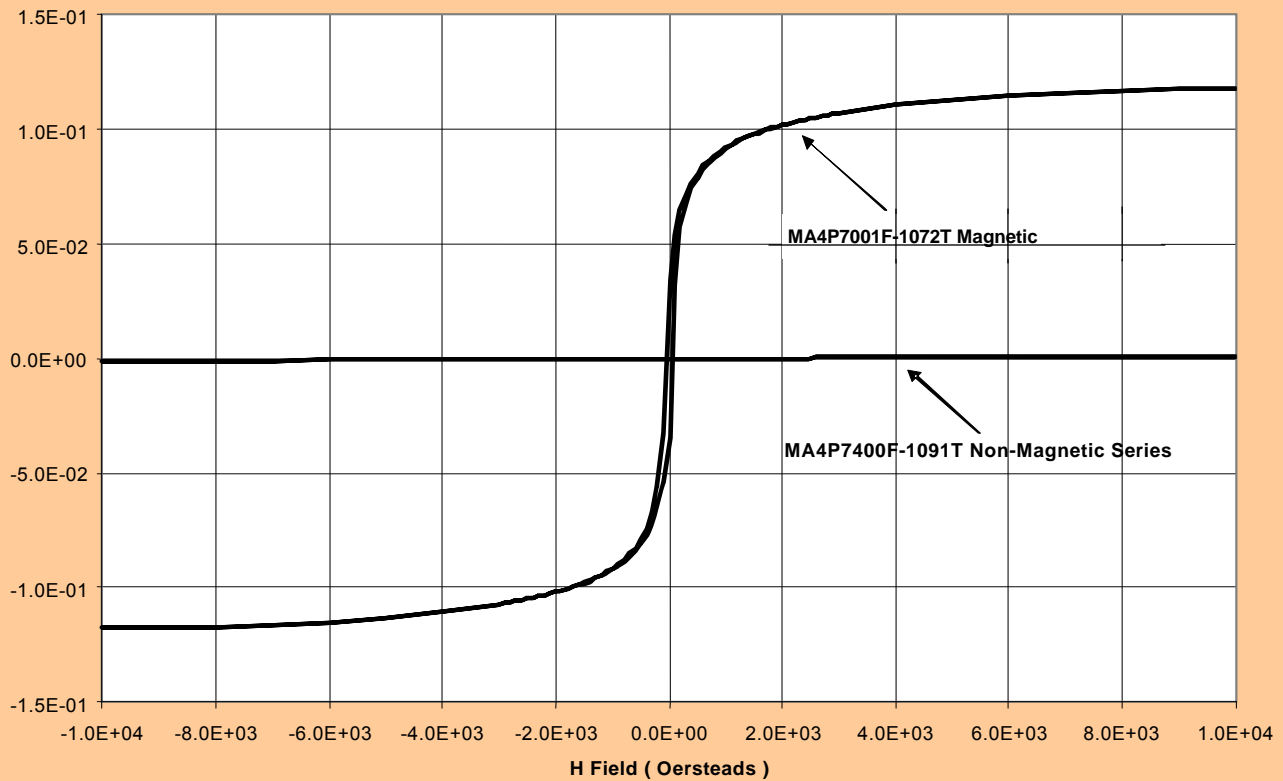
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Typical Electrical Performance @+25°C



Typical Non-Magnetic Performance

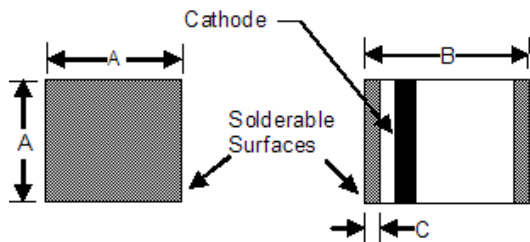
Comparison of Magnetic Moment for MA4P7461F-1072T & MA4P7001F-1072T Magnetic Devices



Typical Magnetic Properties of Non-Magnetic MA4P7461F-1072T Device vs. Conventional MA4P7001F-1072T Magnetic Device

Magnetic Property	MA4P7452F-1072T	MA4P7002F-1072T
Saturation Moment (EMU) @ H = H _{MAX} Oersteds	2.3 x E-4	2.1 x E-2
Remanance Moment (EMU) @ H = 0 Oersteds	4.2 x E-8	7.1 x E-3
Coercivity (Oersteds) @ EMU = 0 Moment	1.0	59.2

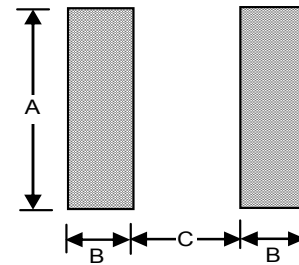
1072 MELF Surface Mount Package



Dimension	Inches	Milimeters
A	0.093	2.36
B	0.050	1.27
C	0.060	1.52

Circuit Pad Layout for MELF Diodes

Dimension	Package Style 1072	
	inches	mm
A	0.093	2.36
B	0.050	1.27
C	0.060	1.52



MELF Assembly Recommendations

- ◆ Devices may be soldered using standard 60Sn/40Pb or RoHS compliant solders. All solderable surfaces of MELF devices are tin plated 50 μ m thick to ensure an optimum connection.
- ◆ For recommended Sn/Pb and RoHS soldering profiles See Application Note [M538](#) on the M/A-COM Tech website.

Ordering Information

Part Number	Package
MA4P7461F-1072T	Tape and Reel



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

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- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
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- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
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- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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